

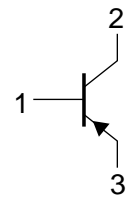
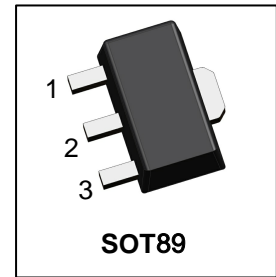
LBTP560Y3T1G

S-LBTP560Y3T1G

PNP transistor

1. FEATURES

- Low collector-emitter saturation voltage.
- High collector current capability.
- High collector current gain.
- High efficiency due to less heat generation.
- Smaller required Printed-Circuit Board (PCB) area.
- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S-prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.



2. DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LBTP560Y3T1G	6PP	1000/Tape&Reel

3. MAXIMUM RATINGS(Ta = 25°C)

Parameter	Symbol	Limits	Unit
Collector–Emitter Voltage	V _{CEO}	-60	V
Collector–Base Voltage	V _{CBO}	-100	V
Emitter–Base Voltage	V _{EBO}	-7	V
Collector Current — Continuous	I _C	-4.3	A
Peak Collector Current (tp ≤ 1 ms)	I _{CM}	-15	A
Junction and Storage temperature	T _J , T _{stg}	-55~+150	°C

4. THERMAL CHARACTERISTICS

Parameter	Symbol	Limits	Unit
Total Device Dissipation, FR-4 Board (Note 1) @ TA = 25°C Derate above 25°C	PD	550 4.4	mW mW/°C
Thermal Resistance, Junction–to–Ambient	R _{θJA}	225	°C/W

1.PCB Size:30.0mm×25.0mm×1.6mm,FR-4 Board;

5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)
OFF CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Collector–Emitter Breakdown Voltage (IC = -10 mA, IB = 0)	VBR(CEO)	-60	-	-	V
Collector–Base Breakdown Voltage (IC = -100 μA, IE = 0)	VBR(CBO)	-100	-	-	V
Emitter–Base Breakdown Voltage (IE = -100 μA, IC = 0)	VBR(EBO)	-7	-	-	V
Collector Cutoff Current (VCB = -80V, IE = 0)	ICBO	-	-	-30	nA
Emitter CutOff Current (VEB = -6 V, IC = 0)	IEBO	-	-	-30	nA
Collector-Emitter cutoff Current (VCE = -60V, IB = 0)	ICEO	-	-	-10	μA

ON CHARACTERISTICS (Note 2)

DC Current Gain (VCE = -1 V, IC = -10 mA) (VCE = -1 V, IC = -2 A) (VCE = -1 V, IC = -5 A)	HFE	100 100 45	250 200 90	- 300 -	
Collector–Emitter Saturation Voltage (IC = -0.1 A, IB = -10 mA) (IC = -1 A, IB = -100 mA) (IC = -2 A, IB = -200 mA) (IC = -5 A, IB = -500 mA)	VCE(sat)	- - - -	-14 -50 -75 -160	-20 -65 -110 -240	mV
Base–Emitter Saturation Voltage (IC = -5 A, IB = -500 mA)	VBE(sat)	-	-0.95	-1.05	V
Base-Emitter Turn-On Voltage (VCE = -1 V, IC = -5 A)	VBE(on)	-	-0.84	-0.95	V

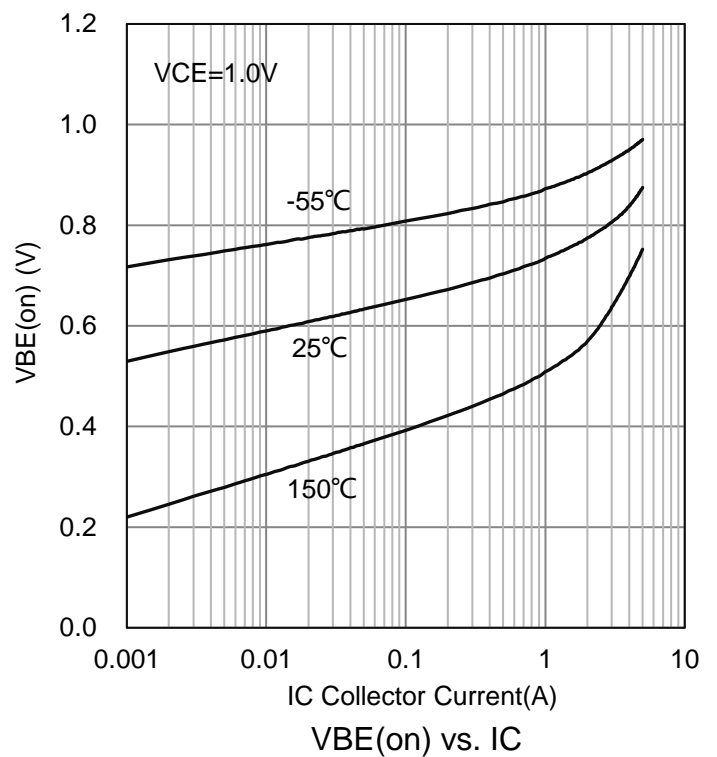
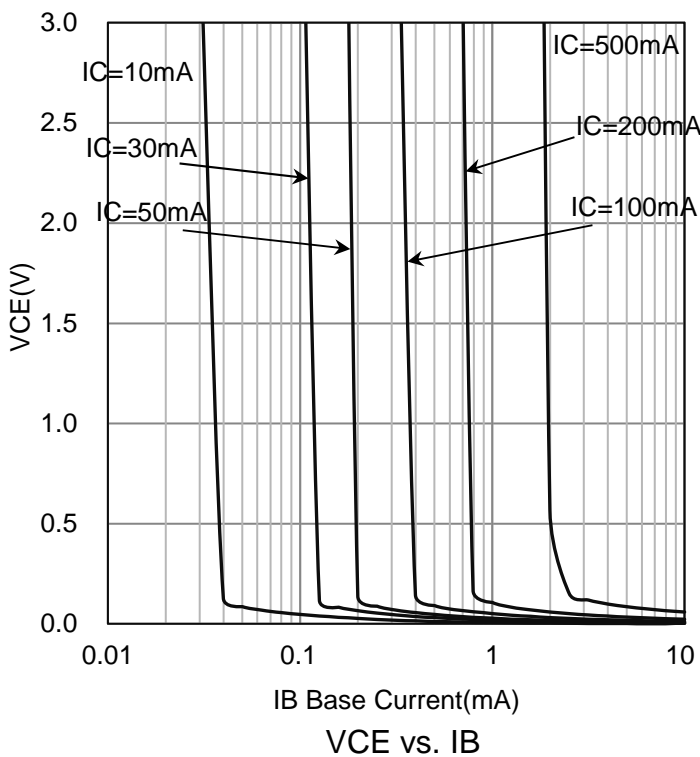
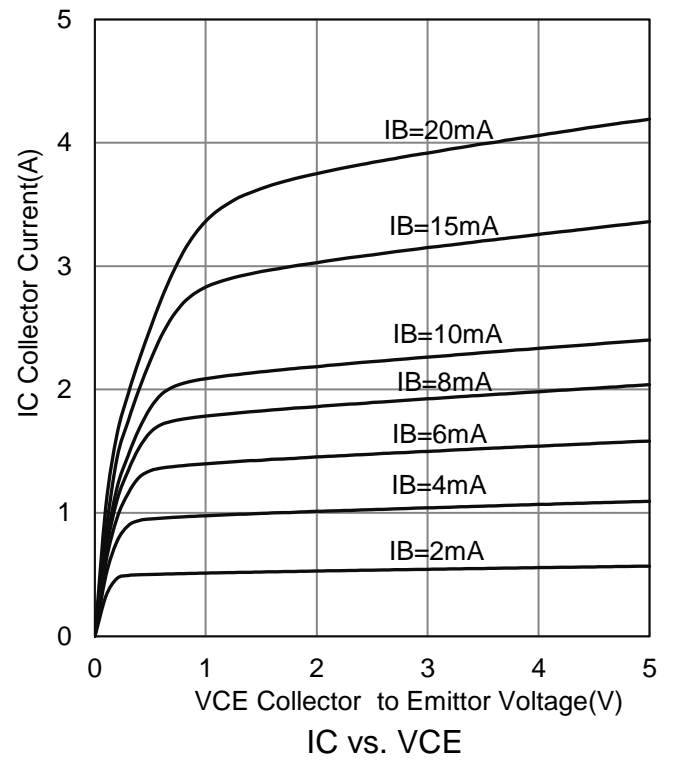
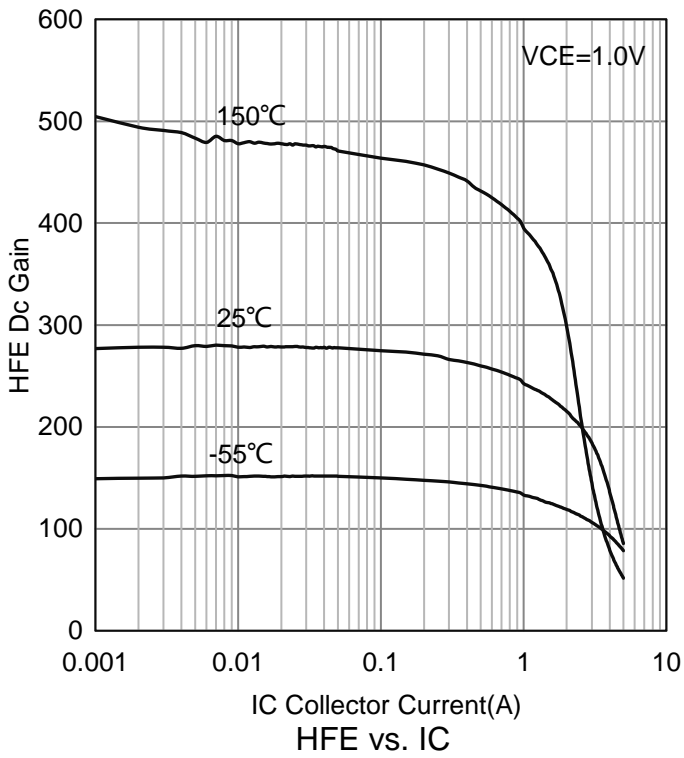
SMALL–SIGNAL CHARACTERISTICS

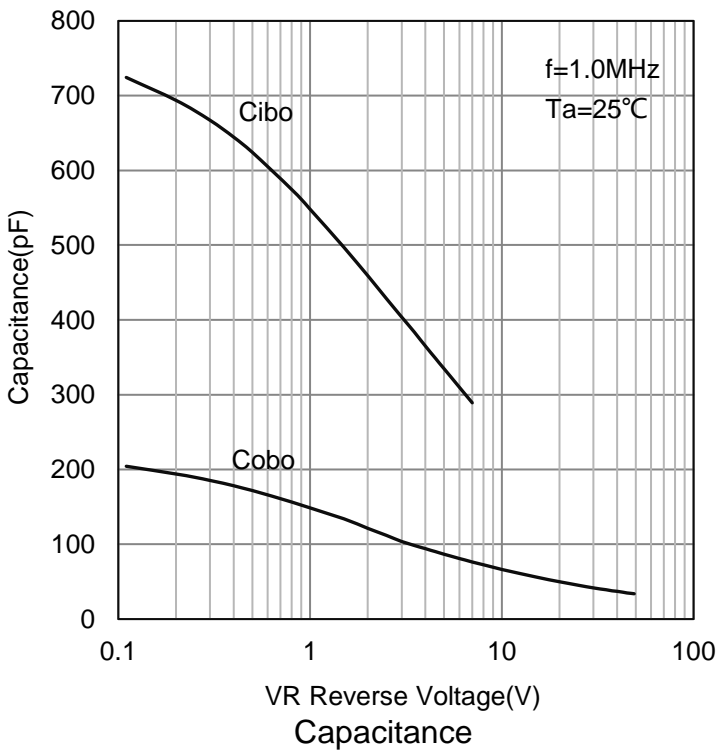
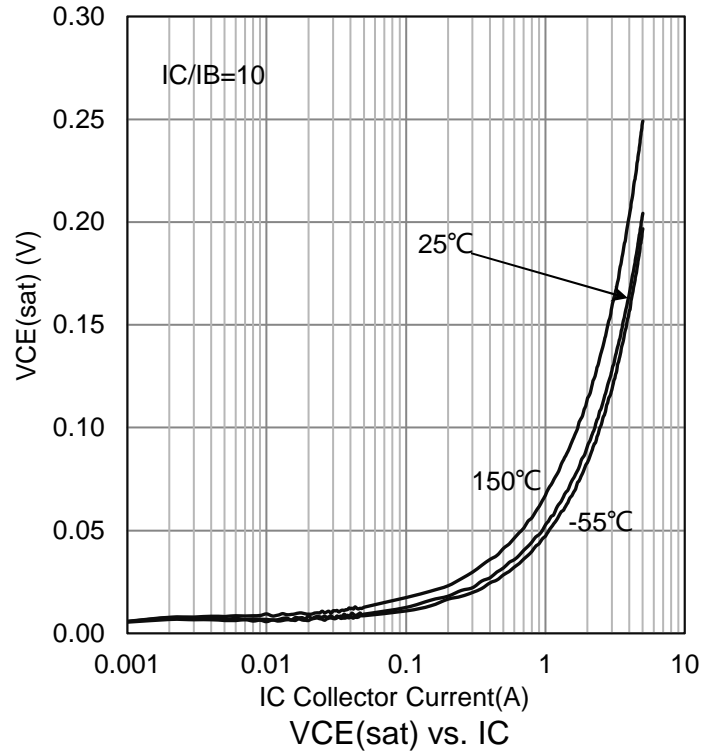
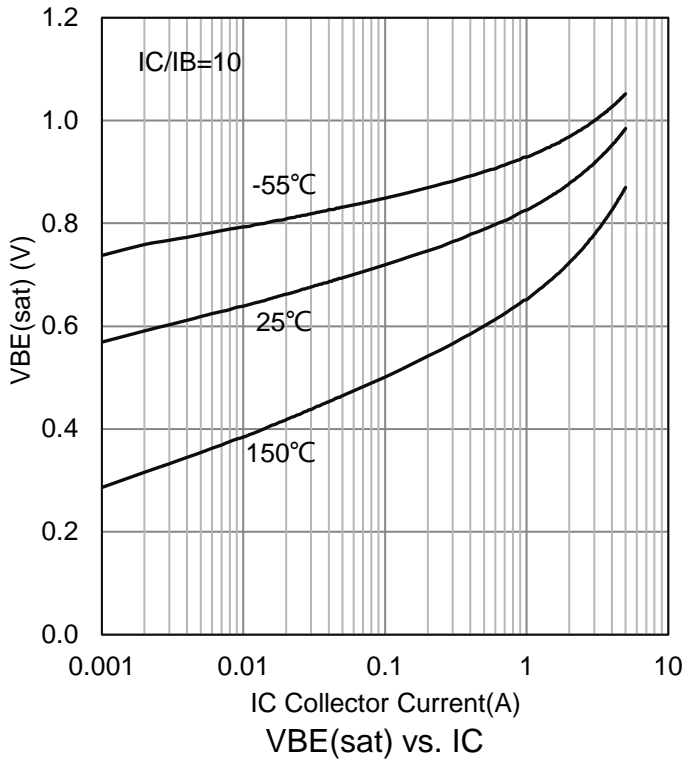
Transitional Frequency (VCE = -10 V, IC = -100 mA, f = 50 MHz)	fT	-	120	-	MHz
Output capacitance (VCB = -10 V, f = 1 MHz)	Cobo	-	48	-	pF

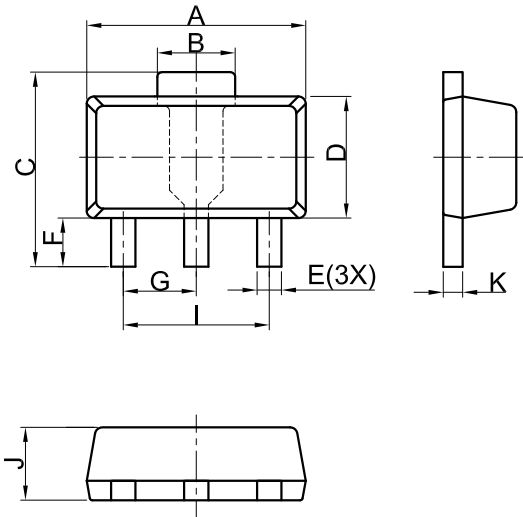
SWITCHING CHARACTERISTICS

Switching times (IC = -1A, VCC = -10V, IB1 = IB2 = -100mA)	td(on)	-	39	-	ns
Switching times (IC = -1A, VCC = -10V, IB1 = IB2 = -100mA)	td(off)	-	370	-	

2.Pulse Test: Pulse Width ≤300 μs, Duty Cycle ≤2.0%.

6.ELECTRICAL CHARACTERISTICS CURVES


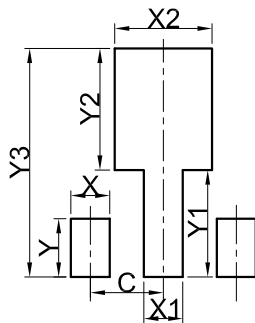
6.ELECTRICAL CHARACTERISTICS CURVES(Con.)


7.OUTLINE AND DIMENSIONS


SOT89			
DIM	MIN	NOR	MAX
A	4.30	4.50	4.70
B	1.40	1.60	1.80
C	3.90	4.00	4.25
D	2.30	2.50	2.70
E	0.40	0.50	0.58
F	0.90	1.00	1.20
G	1.50 BSC		
I	3.00 BSC		
J	1.40	1.50	1.60
K	0.34	0.40	0.50
All Dimensions in mm			

GENERAL NOTES

1. Top package surface finish Ra0.4±0.2um
2. Bottom package surface finish Ra0.7±0.2um
3. Side package surface finish Ra0.4±0.2um
4. Protrusion or Gate Burrs shall not exceed 0.10mm per side.

8.SOLDERING FOOTPRINT


SOT89	
DIM	(mm)
X	0.80
Y	1.20
X1	0.80
Y1	2.20
X2	2.00
Y2	2.50
C	1.50
Y3	4.70

DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee. The curve of test items without electric parameter is used as reference only.
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